# TP1600N i

## SCTP1600Nxx

Phase control press-pack thyristor

## FEATURES

- -All difussed design
- -High current capabilities
- -High surge current capabilities
- -High rated voltage
- -High dv/dt
- -Low gate current
- -Dynamic gate
- -Low thermal impedance
- -Compact size and small weight

## APPLICATION

- -High Power drives -DC motor control -High voltage power cuplplies
- -Resistance welding

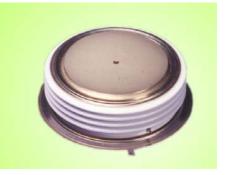


Photo non-contractual

## **TECHNICAL SPECIFICATION**

### **Electrical properties**

Parameter		Test conditions	Value
Repetitive reverse voltage	$V_{RRM}$	SCTP1600N12	1200 V
		SCTP1600N16	1600 V
Reverse current	I <sub>RRM</sub>	Tj <sub>max</sub>	100 mA
Average on-state current	I <sub>AV</sub>	T <sub>C</sub> =70°C	1600 A
R.M.S. Forward current	I <sub>RMS</sub>		2500 A
Surge current	I <sub>TSM</sub>	10ms, Tj <sub>max,</sub> 0.8V <sub>RRM</sub>	27000 A
l <sup>2</sup> t value	l <sup>2</sup> t		3600x10 <sup>3</sup> A <sup>2</sup> s
On-state voltage max.	V <sub>T</sub>	I <sub>TM</sub> =1500A, Tj <sub>max</sub>	1,20 V
Treshold voltage	Vo		0,78 V
Slope resistance	ro		0,18 mOhm
Latching current	ΙL	Tj=25°C, V <sub>D</sub> =12V	1000 mA
Holding current	Ι <sub>Η</sub>	Tj=25°C, V <sub>D</sub> =12V	250 mA
Circuit conmutated turno-off time (typical)	tq	Tj=125°C, I <sub>TM</sub> =250A, di <sub>R</sub> /dt=25A/µs, V <sub>D</sub> =0,67V <sub>DRM</sub> , V <sub>RM</sub> =100V.	100 µs
Turn-on time (typical)	t <sub>on</sub>	I <sub>TM</sub> =100A, V <sub>DM</sub> =100V	12 µs
Rate of change of current	di/dt	Tj=125°C, I <sub>TM</sub> =3I <sub>AV</sub> , V <sub>D</sub> =0,67V <sub>DRM</sub> , f=50Hz, I <sub>GM</sub> =1A, di <sub>G</sub> /dt=1A/μs	200 A/µs
Rate of rise of voltage	dv/dt	Tj=125°C, V <sub>D</sub> =0,67V <sub>DRM</sub>	1000 V/µs
Trigger gate current	I <sub>G</sub>	Tj=25°C, V <sub>D</sub> =12V	200 mA
Gate trigger voltage	$V_{G}$	Tj=25°C, V <sub>D</sub> =12V	3 V

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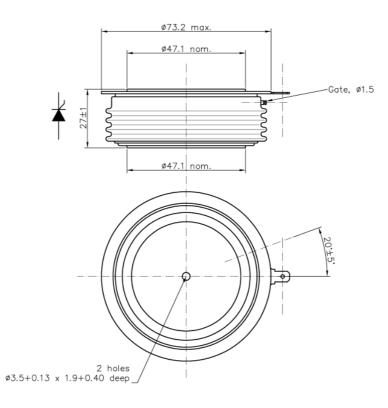
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## **Thermal properties**

Parameter		Test conditions	Value
Max. operating junction temperature	Tj <sub>max</sub>		125 °C
Thermal resistance junction-capsule		DC	0,021 °C/W.
	RTH <sub>i-c</sub>	180° sin	0,021 °C/W.
	тхтт <sub>ј-с</sub>	120° sin	0,0215 °C/W.
		60° sin	0,0225 °C/W.
Thermal resistance capsule-heatsink	$RTH_{c-hs}$		0,01°C/W.
Storage temperature	T <sub>stg</sub>		-40+125°C

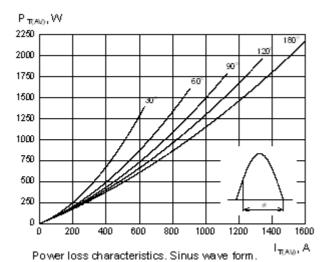
### **Mechanical properties**

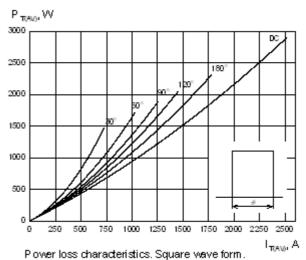
Parameter		Value
Weight	М	480 g
Clamping force	m	22,525 kN

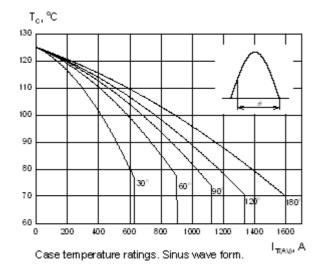


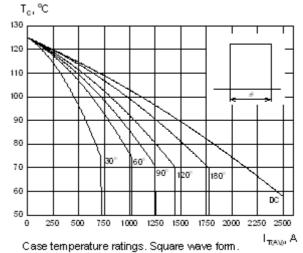
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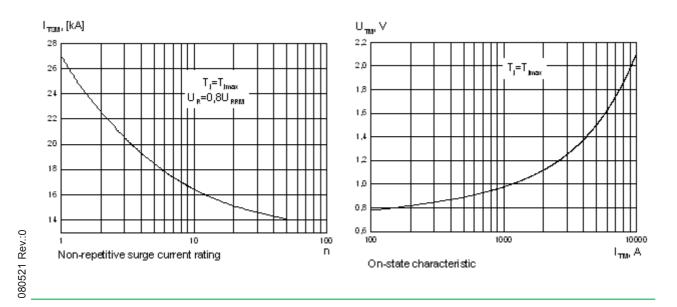






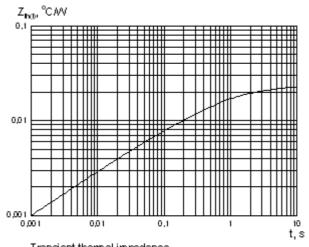




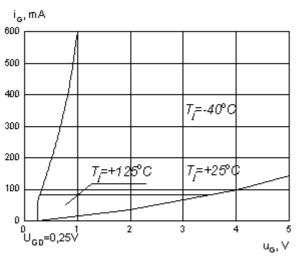




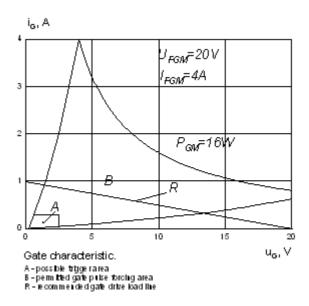
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Gate characteristic. Possible trigger area.





## **Cost Effective Products**

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